

Timetable of RJUSE TeraTech-2021

Plenary: 45 min. talk & 5 min. Q&A

Invited: 25 min. talk & 5 min. Q&A

Contributed: 10 min. talk & 5 min. Q&A

Time in JST Time Zone

1st, Nov. (Mon.)	2nd, Nov. (Tue.)	3rd, Nov. (Wed.)	4th, Nov. (Thu.)
10:15-10:25 Opening		10:15-11:45 Session We1 Carrier Dynamics and Material Properties in THz Regime I:	10:15-12:15 Session Th1 Electronic/Photonic THz Devices and Components I:
10:25-11:15 Session Mo1 Plasmonic THz Devices I: M. S. Shur (Plenary)		J. Kono (Invited) B. Sensale-Rodriguez (Invited) M. Yamashita (Contributed) F. Iwasaki (Contributed)	M. Asada (Invited) K. Kato (Invited) M. Jarrahi (Invited) M. Van Ta (Contributed) D. Nakajima (Contributed)
11:15-11:30 Coffee Break		11:45-12:00 Coffee Break	
11:30-13:00 Session Mo2 Graphene THz Devices I: V. Ryzhii (Invited) V. Perebeinos (Invited) C. Tang (Contributed) K. Tamura (Contributed)	11:30-12:30 Session Tu1 Nanostructured THz Devices: V. V. Mitin (Invited) K. Hirakawa (Invited)	12:00-12:50 Session We2 Superconducting THz Devices: G. N. Goltsman (Plenary)	
13:00-14:15 Lunch	12:30-14:15 Lunch	12:50-14:15 Lunch	12:15-14:15 Lunch
14:15-15:45 Session Mo3 Graphene THz Devices II: S. Ganichev (Invited) Y. M. Meziani (Invited) A. Shirokova (Contributed) V. Semkin (Contributed)	14:15-15:50 Session Tu2 Nonlinear THz Generation: H. Minamide (Plenary) M. Kurnikov (Contributed) A. Novokovskaya (Contributed) V. Trukhin (Contributed)	14:15-16:05 Session We3 THz Wireless Communications: T. Nagatsuma (Plenary) M. Fujishima (Invited) G. Ducournau (Invited)	14:15-16:15 Session Th2 Electronic/Photonic THz Devices and Components II: D. Ponomarev (Invited) E. Castro-Camus (Invited) A. Tredicucci (Invited) M. Helm (Invited)
15:45-16:00 Coffee Break	15:50-16:05 Coffee Break	16:05-16:20 Coffee Break	16:15-16:30 Coffee Break
16:00-17:30 Session Mo4 Narrow Bandgap Materials for THz Devices I: S. V. Morozov (Invited) A. A. Dubinov (Invited) N. Mikhailov (Invited)	16:05-17:50 Session Tu3 Graphene THz Devices III: M. Lemme (Invited) D. Svintsov (Invited) V. Kachorovskii (Invited) S. Zanonno (Contributed)	16:20-17:35 Session We4 Plasmonic THz Devices II: D. Fateev (Invited) T. Negoro (Contributed) Y. Sasaki (Contributed) A. Shabanov (Contributed)	16:30-17:20 Session Th3 Carrier Dynamics and Material Properties in THz Regime II: W. Knap (Plenary)
17:30-17:45 Coffee Break	17:50-18:05 Coffee Break	17:35-17:50 Coffee Break	17:20-17:35 Coffee Break
17:45-19:00 Session Mo5 2D Electron Systems for THz Devices: A. S. Petrov (Contributed) A. S. Petrov (Contributed) W. Michailow (Contributed) S. Mikhailov (Invited)	18:05-19:05 Session Tu4 Narrow Bandgap Materials for THz Devices II: R. Matsunaga (Invited) F. Teppe (Invited)	17:50-19:05 Session We5 THz Measurement Methods I: S. Komiyama (Invited) M. Tonouchi (Invited) H. Momiyama (Contributed)	17:35-18:50 Session Th4 THz Measurement Methods II: C. Otani (Invited) K. Murate (Invited) T. Yoshizumi (Contributed)
			18:50-19:00 Closing